

## Product Summary

| $BV_{DSS}$ | $R_{DS(ON)}$ Max         | $I_D$ Max<br>$T_A = +25^\circ C$ |
|------------|--------------------------|----------------------------------|
| 60V        | $2\Omega @ V_{GS} = 10V$ | 380mA                            |
|            | $3\Omega @ V_{GS} = 5V$  | 310mA                            |

## Description

This MOSFET has been designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

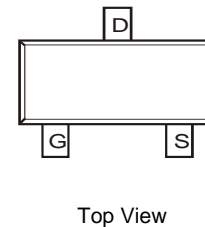
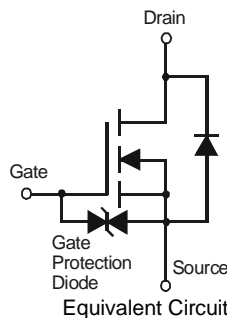
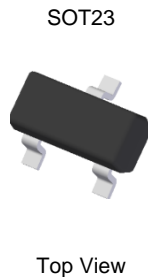
- Motor Control
- Power Management Functions
- Backlighting

## Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected Up To 2kV**
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

## Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.008 grams (Approximate)

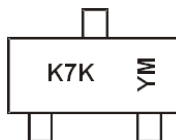


## Ordering Information (Note 5)

| Part Number | Compliance | Case  | Packaging         |
|-------------|------------|-------|-------------------|
| 2N7002K-7   | Standard   | SOT23 | 3000/Tape & Reel  |
| 2N7002KQ-7  | Automotive | SOT23 | 3000/Tape & Reel  |
| 2N7002K-13  | Standard   | SOT23 | 10000/Tape & Reel |
| 2N7002KQ-13 | Automotive | SOT23 | 10000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to <https://www.diodes.com/quality/>.
  5. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



K7K = Product Type Marking Code  
 YM or YM = Date Code Marking  
 Y or Y = Year (ex: F = 2018)  
 M = Month (ex: 9 = September)

### Date Code Key

| Year | 2006 | ~ | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 |
|------|------|---|------|------|------|------|------|------|------|------|------|------|
| Code | T    | ~ | F    | G    | H    | I    | J    | K    | L    | M    | N    | O    |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code  | 1   | 2   | 3   | 4   | 5   | 6   | 7   | 8   | 9   | O   | N   | D   |

**Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic  |                 |  | Symbol    | Value      | Unit |
|---|-----------------|--|-----------|------------|------|
| Drain-Source Voltage  |                 |  | $V_{DSS}$ | 60         | V    |
| Gate-Source Voltage   |                 |  | $V_{GSS}$ | $\pm 20$   | V    |
| Continuous Drain Current (Note 7) $V_{GS} = 10\text{V}$                 | Steady State    | $T_A = +25^\circ\text{C}$<br>$T_A = +70^\circ\text{C}$ | $I_D$     | 380<br>300 | mA   |
|   | $t < 5\text{s}$ | $T_A = +25^\circ\text{C}$<br>$T_A = +70^\circ\text{C}$ | $I_D$     | 430<br>340 | mA   |
| Continuous Drain Current (Note 7) $V_{GS} = 5\text{V}$                  | Steady State    | $T_A = +25^\circ\text{C}$<br>$T_A = +70^\circ\text{C}$ | $I_D$     | 310<br>240 | mA   |
|   | $t < 5\text{s}$ | $T_A = +25^\circ\text{C}$<br>$T_A = +70^\circ\text{C}$ | $I_D$     | 350<br>270 | mA   |
| Maximum Continuous Body Diode Forward Current (Note 7)                  |                 |  | $I_S$     | 0.5        | A    |
| Pulsed Drain Current (10 $\mu\text{s}$ Pulse, Duty Cycle = 1%) (Note 7) |                 |  | $I_{DM}$  | 1.2        | A    |

**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic                                   |                 |  | Symbol          | Value       | Unit               |
|--|-----------------|--|-----------------|-------------|--------------------|
| Total Power Dissipation (Note 6)                 |                 |  | $P_D$           | 370         | mW                 |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State    |  | $R_{\theta JA}$ | 357         | $^\circ\text{C/W}$ |
|  | $t < 5\text{s}$ |  |                 | 292         |                    |
| Total Power Dissipation (Note 7)                 |                 |  | $P_D$           | 540         | mW                 |
| Thermal Resistance, Junction to Ambient (Note 7) | Steady State    |  | $R_{\theta JA}$ | 240         | $^\circ\text{C/W}$ |
|  | $t < 5\text{s}$ |  |                 | 197         |                    |
| Thermal Resistance, Junction to Case (Note 7)    |                 |  | $R_{\theta JC}$ | 91          |                    |
| Operating and Storage Temperature Range          |                 |  | $T_J, T_{STG}$  | -55 to +150 | $^\circ\text{C}$   |

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic                          | Symbol       | Min | Typ  | Max      | Unit          | Test Condition  |
|---|--------------|-----|------|----------|---------------|---|
| <b>OFF CHARACTERISTICS (Note 8)</b>     |              |     |      |          |               |   |
| Drain-Source Breakdown Voltage          | $BV_{DSS}$   | 60  | —    | —        | V             | $V_{GS} = 0\text{V}, I_D = 10\mu\text{A}$   |
| Zero Gate Voltage Drain Current         | $I_{DSS}$    | —   | —    | 1.0      | $\mu\text{A}$ | $V_{DS} = 60\text{V}, V_{GS} = 0\text{V}$   |
| Gate-Source Leakage                     | $I_{GSS}$    | —   | —    | $\pm 10$ | $\mu\text{A}$ | $V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$                                       |
| <b>ON CHARACTERISTICS (Note 8)</b>      |              |     |      |          |               |   |
| Gate Threshold Voltage                  | $V_{GS(TH)}$ | 1.0 | 1.6  | 2.5      | V             | $V_{DS} = 10\text{V}, I_D = 1\text{mA}$   |
| Static Drain-Source On-Resistance       | $R_{DS(ON)}$ | —   | —    | 2.0      | $\Omega$      | $V_{GS} = 10\text{V}, I_D = 0.5\text{A}$  |
|   |              | —   | —    | 3.0      |               | $V_{GS} = 5\text{V}, I_D = 0.05\text{A}$  |
| Forward Transfer Admittance             | $ Y_{fs} $   | 80  | —    | —        | ms            | $V_{DS} = 10\text{V}, I_D = 0.2\text{A}$  |
| Diode Forward Voltage                   | $V_{SD}$     | —   | 0.75 | 1.1      | V             | $V_{GS} = 0\text{V}, I_S = 115\text{mA}$  |
| <b>DYNAMIC CHARACTERISTICS (Note 9)</b> |              |     |      |          |               |   |
| Input Capacitance                       | $C_{iss}$    | —   | 30   | 50       | pF            | $V_{DS} = 25\text{V}, V_{GS} = 0\text{V}$<br>$f = 1.0\text{MHz}$                    |
| Output Capacitance                      | $C_{oss}$    | —   | 4.2  | 25       | pF            |   |
| Reverse Transfer Capacitance            | $C_{rss}$    | —   | 2.9  | 5.0      | pF            |   |
| Gate Resistance                         | $R_g$        | —   | 133  | —        | $\Omega$      | $f = 1\text{MHz}, V_{GS} = 0\text{V}, V_{DS} = 0\text{V}$                           |
| Total Gate Charge                       | $Q_g$        | —   | 0.3  | —        | nC            | $V_{GS} = 4.5\text{V}, V_{DS} = 10\text{V},$<br>$I_D = 250\text{mA}$                |
| Gate-Source Charge                      | $Q_{gs}$     | —   | 0.2  | —        | nC            |   |
| Gate-Drain Charge                       | $Q_{gd}$     | —   | 0.08 | —        | nC            |   |
| Turn-On Delay Time                      | $t_{D(ON)}$  | —   | 3.9  | —        | ns            | $V_{DD} = 30\text{V}, V_{GS} = 10\text{V},$<br>$R_G = 25\Omega, I_D = 200\text{mA}$ |
| Turn-On Rise Time                       | $t_R$        | —   | 3.4  | —        | ns            |   |
| Turn-Off Delay Time                     | $t_{D(OFF)}$ | —   | 15.7 | —        | ns            |   |
| Turn-Off Fall Time                      | $t_F$        | —   | 9.9  | —        | ns            |   |

- Notes:
6. Device mounted on FR-4 PCB, with minimum recommended pad layout.
  7. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
  8. Short duration pulse test used to minimize self-heating effect.
  9. Guaranteed by design. Not subject to product testing.

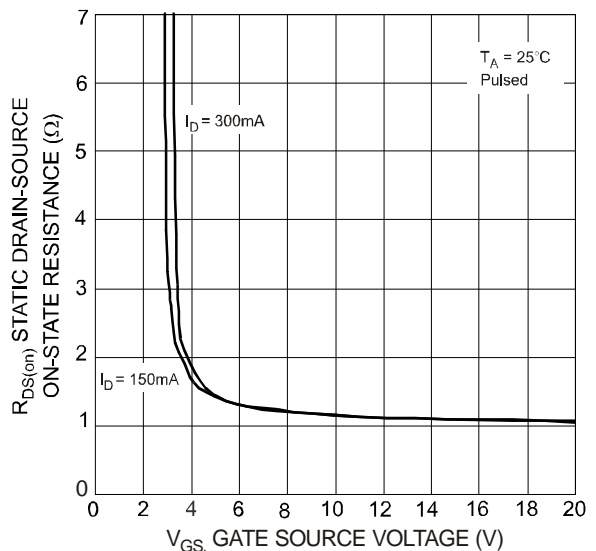
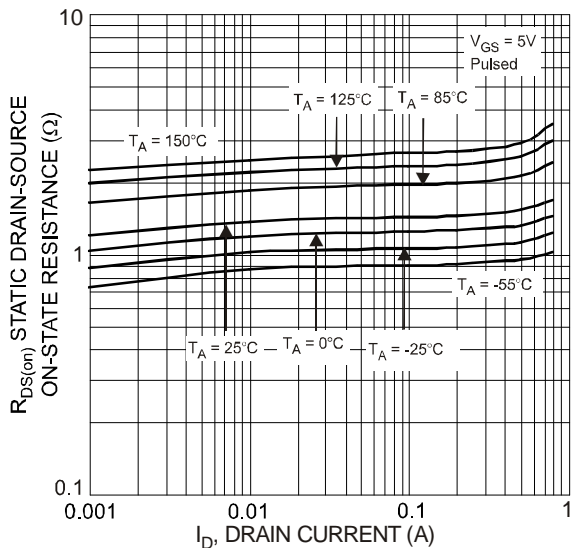
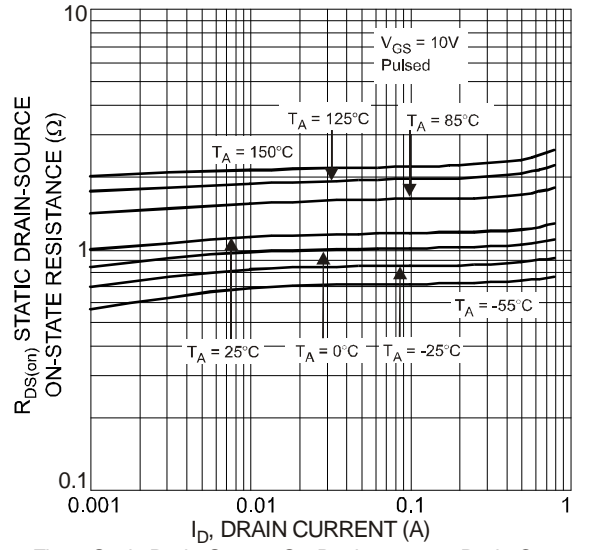
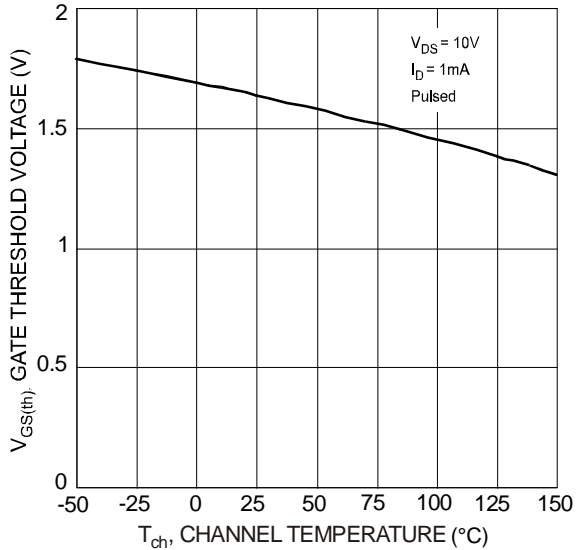
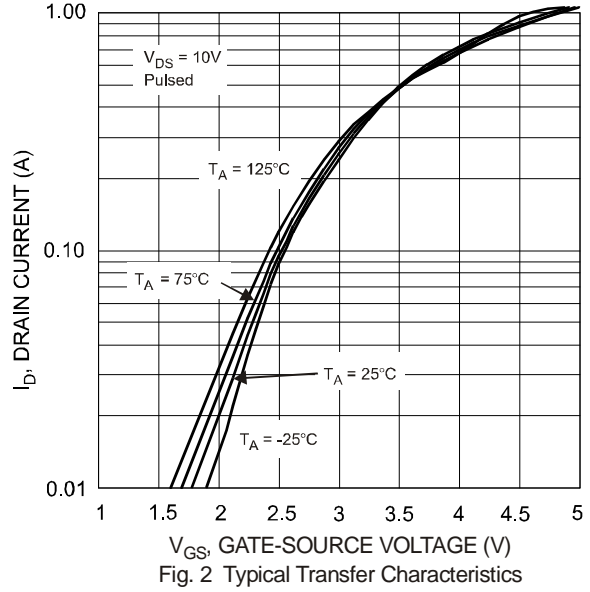
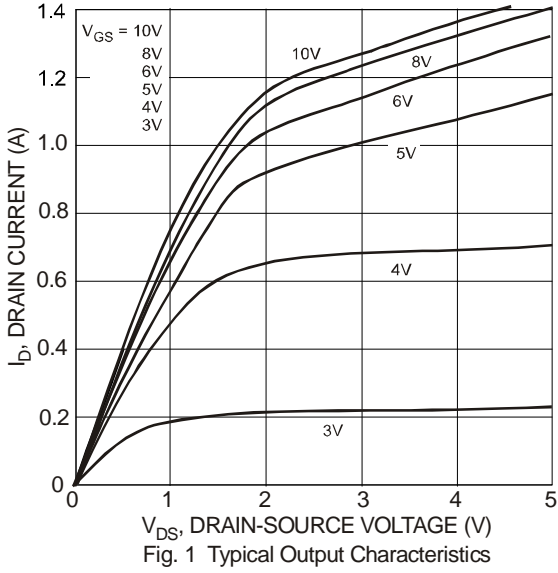


Fig. 5 Static Drain-Source On-Resistance vs. Drain Current

Fig. 6 Static Drain-Source On-Resistance vs. Gate-Source Voltage

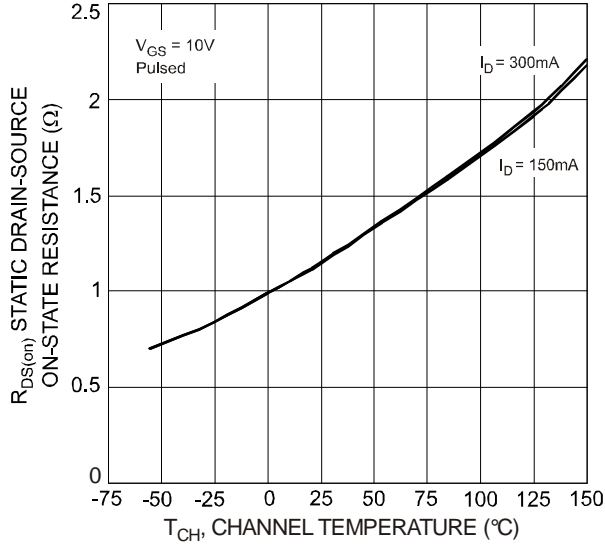


Fig. 7 Static Drain-Source On-State Resistance vs. Channel Temperature

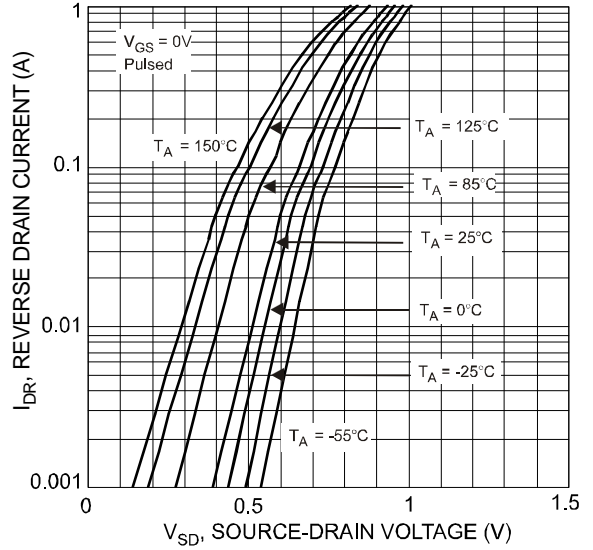


Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

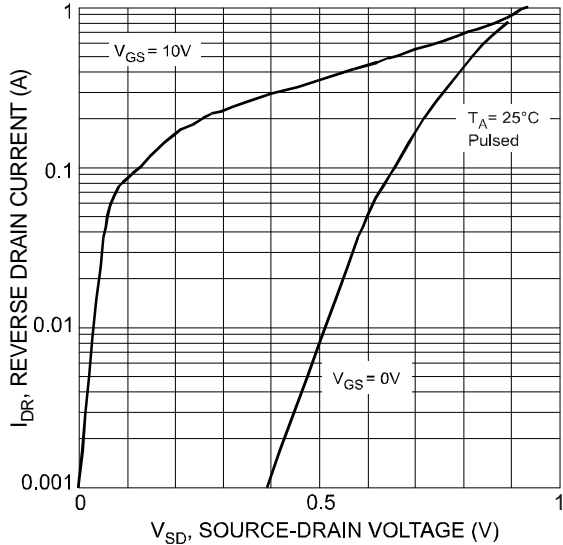


Fig. 9 Reverse Drain Current vs. Source-Drain Voltage

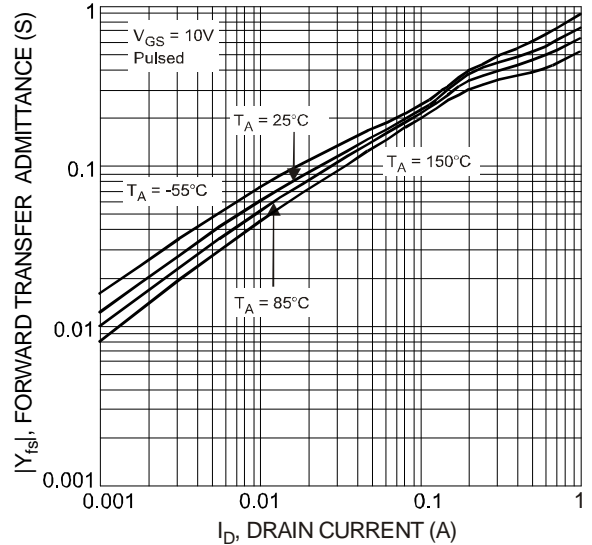


Fig. 10 Forward Transfer Admittance vs. Drain Current

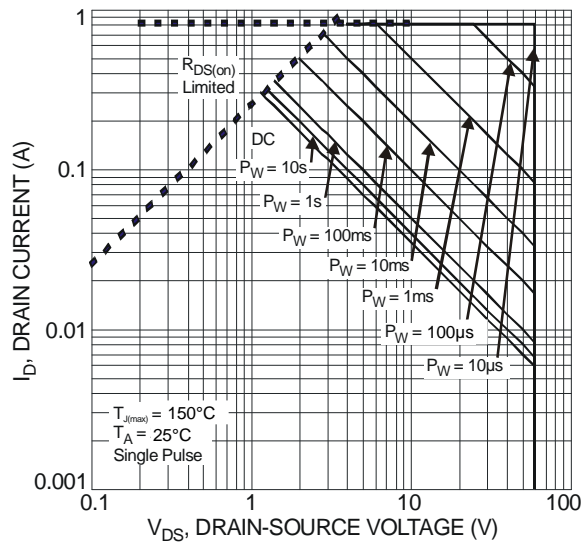


Fig. 11 Safe Operation Area

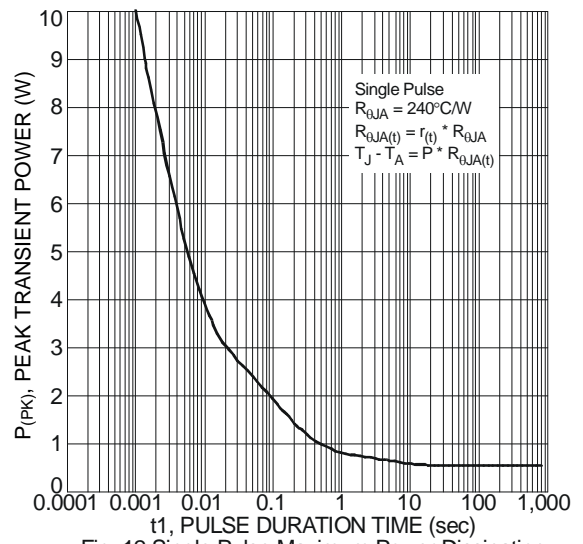
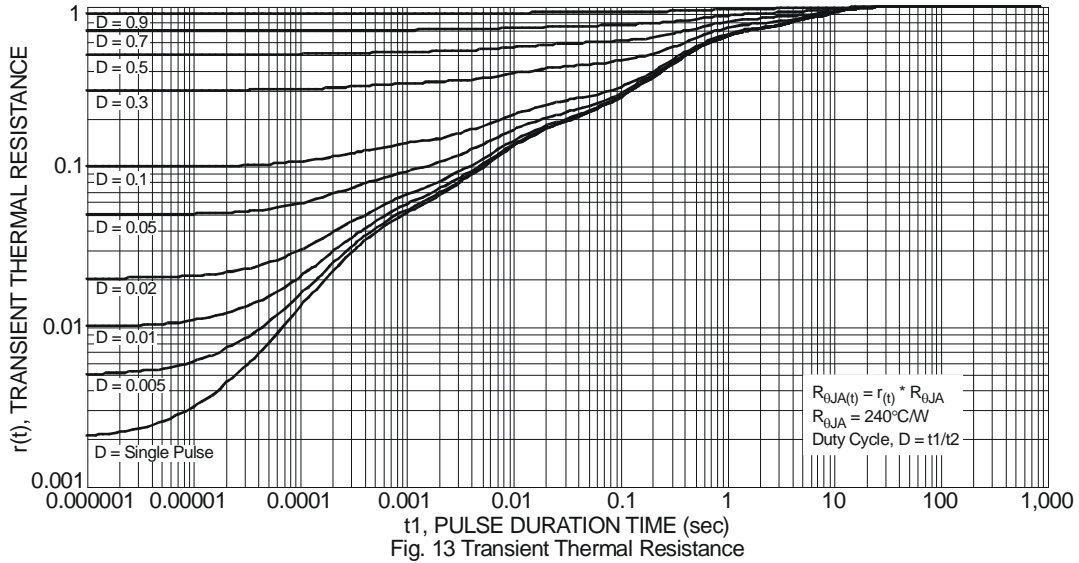


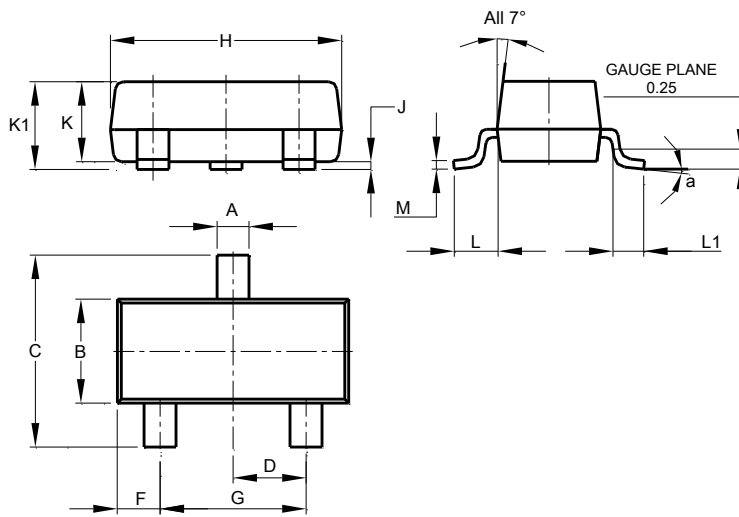
Fig. 12 Single Pulse Maximum Power Dissipation



**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23**

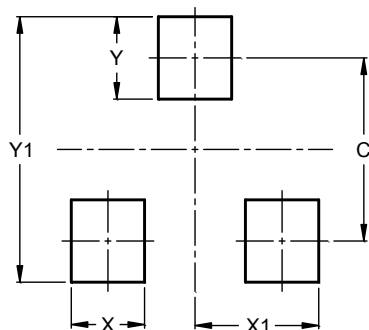


| SOT23                |       |       |       |
|----------------------|-------|-------|-------|
| Dim                  | Min   | Max   | Typ   |
| A                    | 0.37  | 0.51  | 0.40  |
| B                    | 1.20  | 1.40  | 1.30  |
| C                    | 2.30  | 2.50  | 2.40  |
| D                    | 0.89  | 1.03  | 0.915 |
| F                    | 0.45  | 0.60  | 0.535 |
| G                    | 1.78  | 2.05  | 1.83  |
| H                    | 2.80  | 3.00  | 2.90  |
| J                    | 0.013 | 0.10  | 0.05  |
| K                    | 0.890 | 1.00  | 0.975 |
| K1                   | 0.903 | 1.10  | 1.025 |
| L                    | 0.45  | 0.61  | 0.55  |
| L1                   | 0.25  | 0.55  | 0.40  |
| M                    | 0.085 | 0.150 | 0.110 |
| a                    | 0°    | 8°    | --    |
| All Dimensions in mm |       |       |       |

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23**



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 2.0           |
| X          | 0.8           |
| X1         | 1.35          |
| Y          | 0.9           |
| Y1         | 2.9           |

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